Robust Half-M etallic Character and Large Oxygen M agnetism in a Perovskite Cuprate

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The new perovskite cuprate material Sr₈CaRe₃Cu₄O₂₄, which behaves ferrim agnetically and shows an unusually high Curie temperature (T_c 440 K), is found from density-functional theory calculation to display several suprising properties after hole doping or chemical substitution: (1) Halfmetal (HM) is realized by replacing Rewith W or Mowhile T_c remains high; (2) hole-doped Sr₈CaRe₃Cu₄O₂₄ is also HM with high T_c . Moreover, we nd that the O atoms will carry a large magnetic moment after hole doping, which is in sharp contrast with the generally accepted concept that magnetism in solid requires partially led shells of d or f electrons in cations. The material Sr₈CaRe₃Cu₄O₂₄ is therefore expected to provide a very useful platform for material design and development.

Spin-based electronics, or spintronics, is currently a rather hot topic, which o ers opportunities for new generation of multifunctional devices combining traditional charge-based microelectronic with spin-dependent e ects [1]. An ideal component for such devices is half-m etallic ferrom agnet, which is metallic for one spin channel and insulating for the other [2]. The search for HM materials with high T_c is intense in recent years [3, 4]. Up to present, many works focus on the perovskite transition-metal oxides, in particular the M n-based and Fe-based compounds [5, 6]. To nd other new HM compounds with T_c above room temperature is of both fundamental and technological importance.

Since ferrom agnetic (FM) cuprates are very rare, and usually show rather low T_c , they have not been considered seriously as candidates of usefulm agnetic material. Recently a new perovskite cuprate material Sr_8C aR $e_3Cu_4O_{24}$ was synthesized [7]. This cuprate forms the cubic perovskite ABO₃ structure with space group Pm 3m. The A-sites are occupied by Sr exclusively, Ca, Re and Cu are located at the B-sites in an ordered way, and the unit cell contains eight perovskite-like blocks. A coording to the symmetry, the 24 O atoms in unit cell can be sorted into three kinds, O 1, O 2 and O 3, the four Cu atoms are sorted into two kinds, one Cu1 and three Cu2 [7]. This material has some unique physical properties: it is similar in structure to the cuprates show ing high-temperature superconductivity upon carrier doping, while possesses a net magnetization; its T_c is over room temperature (440K), much higher than other known cuprates. Unfortunately, this compound is an insulator, and cannot show any magnetoresistance. Therefore, it is interesting to nd a way to make this compound electrically transportable meanwhile keeping its high T_c. There are two well-known methods to tailor the properties of perovskite materials: B-site substitution and carrier doping. The form erm odi es the band structure while the latter mainly shifts the Ferm i level. A s revealed in this Letter, this cuprate show s several peculiar properties after appropriate B-site substitution and carrier doping.

First let us consider the B-site elem ent substitution. A valuable insight for possible material developing is available starting from the band structure of $Sr_8CaRe_3Cu_4O_{24}$ [8]. In Fig. 1 we show schem atically the minority-spin e_g band of Cu1 and e_g -like band of Cu2, and the p band of O2, noting that other bands have sm all contributions to states near the Ferm i level and can be neglected for a qualitative argum ent. The minority-spin e_g bands of Cu1 and Cu2 are distributed on the two sides of the Ferm i level, with a large interval between the two regions as shown in Fig.1 (a). Due to the Jahn-Teller distortion caused by Re (the (010) plane is shown in Fig. 1 (a)), the degeneracy of the e_g band of Cu2 is lifted and the $d_{x^2-y^2}$ band becomes fully occupied. If one substitutes Re by some other 5d or 4d elements with sm aller electronegativity, the Jahn-Teller distortion in the oxygen octahedron centered at Cu2 should decrease. The splitting of e_g band of Cu2 should decrease signi cantly, and as the result, it may cross the Ferm i level as shown in Fig.1 (b). Tungsten (M) and molybdenum (M o), the elements at the left column of Re in the Periodic Table, can be good candidates for this purpose. Since substituting Re with other elements will not a ect much the bands of Cu1, the spin-up channel therefore remains insulating. Same as $Sr_8CaRe_3Cu_4O_{24}$ [8], the spin-up e_g band of Cu2 are partially occupied, which supports the strong pd hybridization. Therefore, it is expected that substituting Re by W or M ow ill result in a HM with high T_c . The above idea is veri ed by accurate density-functional theory calculations as following.

Calculations have been performed with the W EN 2K package[9], which uses a full-potential, all electron APW + lo m ethod that allows one to carry out total energy calculations of high precision. We adopt the standard generalized gradient approximation (GGA) [10], use the LSDA+U m ethod [11] to treat the electron-electron interaction e ects with U = 10 eV and J = 120 eV for the d orbital of Cu [12]. All the results shown in the following are based on the

fully optim ized structure. We have also con med that the main results are robust and do not change with the values of parameters.

For Sr_BCaW _3Cu_4O_{24} we calculate both ferrin agnetic (FiM) and FM con gurations for Cu1 and Cu2 m om ents. The spin-up eg band of Cu1 and spin-down d_{3z^2} _r^2 band of Cu2 are partially occupied as shown in Fig. 2, while the m a jority-spin bands are fully occupied. Therefore, the m agnetic properties of Sr_BCaW _3Cu_4O_{24} is similar to that of Sr_BCaRe_3Cu_4O_{24} [8]. The ground state is FM; the m agnetic m om ents are carried m ainly by the Cu ions; the total m om ent per unit cell and the m om ents at Cu1 and Cu2 are 4.00, -0.89, and 1.02 _B respectively. The orbital ordering in the d bands of Cu1 and Cu2 revealed in Ref. [8] still exists, which induces a large hybridization with the pz orbital of 0.2, corresponding to the strong pd bond, and produces a strong superexchange interaction between the m agnetic m om ents at Cu1 and Cu2. A s the result, relative to the FM con guration, the FM con guration gains 0.046 Ry per form ula unit. C om paring with the same energy di erence of 0.036 Ry for Sr_BC aRe_3Cu_4O_{24}, we predict that the T_c of Sr_BCaW _3Cu_4O_{24} should be higher than 440 K. A fler substituting Re by W, the Jahn-Teller distortion in the oxygen octahedron centered at Cu2 becomes rather sm all [13], and as shown in Fig. 2 the splitting of eg orbitals of Cu2 cross the Ferm i level, while the spin-up channel is still insulating as shown in Fig. 2, the new material Sr_BCaW _3Cu_4O_{24} is a HM .

Since M o and W lie at the same column of periodic table, the properties of $Sr_8C aM o_3C u_4O_{24}$ are similar to that of $Sr_8C aW_3C u_4O_{24}$. The energy di erence between FiM and FM con guration is also large, so one can expect that $Sr_8C aM o_3C u_4O_{24}$ still has high T_c . A s expected, the Jahn-Teller distortion in the oxygen octahedron centered at C u2 is also rather sm all. As a result, the spin-down channel is m etallic and the spin-up one is insulating as shown in Fig. 3. Therefore, $Sr_8C aM o_3C u_4O_{24}$ is also a HM with high T_c .

Now let us turn to the e ect of hole doping. It is interesting to note that, as shown schematically in Fig.1 (c), in $Sr_8CaRe_3Cu_4O_{24}$ the $p_x + p_y$ band of 02 is rather narrow and just below the Ferm i level [14]. From the view of a rigid band model, doping hole shifts the Ferm i level dow nward and causes it to cross the narrow $p_x + p_y$ band of 02. Therefore, we expect that this compound may display some peculiar properties related to 0 atom s after hole doping. In order to keep the band structure, hole doping is realized for example by A-site element substitution. Since the A -site substitution can be treated successfully by the virtual-crystal approximation (VCA) [15], we employ it in the present study to calculate the electronic and magnetic properties of (Sr₁ _xA_x)₈CaRe₃Cu₄O₂₄ with A stands for a univalent cation. It is found that, di erent from replacing Rewith W or Mo, doping hole has small e ect on the geom etric structure. Since the states just below the Ferm i level are alm ost entirely due to the $p_x + p_y$ band of 02, the d bands of Cu1 and Cu2 are basically una ected by the hole doping. Consequently, same as $Sr_8CaRe_3Cu_4O_{24}$, the ground state is Find, and the energy di erence between FM and Find con guration is still large, which im plies a high T_c of (Sr_{1 x}A_x)₈CaRe₃Cu₄O₂₄. The m agnetic m om ents at Cu1 and Cu2 are alm ost independent of the hole doping as shown in Table I. However, in striking contrast to the parent com pound, 0.2 carries a large m agnetic m om ent after hole doping. At doping concentration x = 0.2, the magnetic moment at 0.2 reaches 0.25 _B, the largest value in literatures [16], and increases further with x as shown in Table I.This phenom enon is very peculiar since it is generally believed that large magnetic moment is carried only by the transition-metal ions with un lled d or f bands.

In order to clarify the origin of large magnetic moment at 02, we show the density of states (DOS) of $(Sr_{0:8}A_{0:2})_8CaRe_3Cu_4O_{24}$ in Fig. 4. (The DOS of other doping x is similar to that of x = 0.2.) The p_z state of 02, which strongly overlaps with the d states of Cu1 and Cu2, forms a wide band. As a result, the exchange splitting of the p_z state of 02 is very small, which has only small contribution to the magnetic moment. So we can conclude that the magnetic moment at 0 is not induced by the magnetic ions Cu, completely di erent from other known materials with magnetic moment at 0 atoms. It is intriguing to note that the spin-up $p_x + p_y$ band of 02 appears in the energy window centered at -1.2 eV and are fully occupied, while the spin-down states are obviously higher in energy than the spin-up one and cross the Ferm i level. This clearly indicates that the exchange splitting of $p_x + p_y$ state of 02 is rather large, and the magnetic moment at 02 is carried mainly by the $p_x + p_y$ state. The mechanism of this exchange splitting can be attributed to the Stoner instability as shown schem atically in Fig.1 (d), namely when the Ferm i level crosses the narrow $p_x + p_y$ band of 02 upon hole doping, the holes fully polarize in order to reduce the total energy. Furtherm ore, the fully polarized holes lead this compound to a HM as can be seen from Fig. 4.

Having clari ed where the magnetic moment of 0 comes from, we try to understand the reason why it is rare in oxides and thus needs ne tuning by material design. As discussed above, there are two essential factors for this phenomenon: the p band of 0 should be narrow and located nearby the Fermi level. It is well known that for perovskite ABO₃ compound, the occupied d state shifts to lower energy and the weight of the 0 2p states increases at the top of valence band as the atom ic number of the transition-metal B increases from 22 (T i) to 29 (Cu) [17]. This is the reason why 0 has the main contribution to the top of valence band of Sr₈C aRe₃Cu₄O₂₄. In contrast, in maganites and many other oxides the state just below the Fermi level com es from the d band of M n mixing with the p band of 0. Since Sr₈C aRe₃Cu₄O₂₄ has the cubic symmetry, the angle of Cu1-O 2-Cu2 is 180⁰, the e_q orbital of Cu1

and the e_g -like orbital of C u2 cannot hybridize with $p_x + p_y$ orbital of 0.2 due to symmetry. On the other hand, the t_{2g} orbitals of C u1 and C u2 are fully occupied, and located at low energy region due to the large C oulom b interaction, therefore the hybridization between these orbitals with the $p_x + p_y$ orbitals of 0.2 is rather small. Consequently, the $p_x + p_y$ band of 0.2 is very narrow, and the D O S is rather high. In contrast, in most perovskite A B O a materials, the B O 6 octahedron tilts with the angle of B -O -B smaller than 180° , consequently the e_g orbital of D c an overlap with the $p_x + p_y$ orbitals of 0, and makes the band of the latter wide, typically of band width of 5-7eV. As it is larger than the intra-atom ic exchange strength, the O is non-magnetic in most oxides. Since the radii of univalent cation A, such as potassium (K), is slightly larger than that of Sr ion, hole doping into Sr₈C aR e_3 C u_4 O $_{24}$ through substituting Sr by K will slightly enlarge the tolerance factor. Therefore, the C uO $_6$ octahedron is not expected to tilt upon such hole doping treatment.

Large m agnetic m om ents at 0 2 upon hole doping are also observed when the LSDA scheme is adopted, which tends to underestim ate the m agnetic m om ent. Therefore, the present result is robust with respect to U, and is likely to be observed experim entally. Our theoretical prediction m ay fail in several exceptional cases, where the system happens to be close to a quantum critical point, or an instability to the triplet superconductivity. In any case, interesting physical properties are expected, and deserve careful experim ental investigations.

In sum m ary, using a density-functional calculation we investigate the e ect of substitution and hole doping on the m aterial $Sr_8C aRe_3C u_4O_{24}$. Our study reveals that a HM with high T_c can be realized by replacing Rewith W or M o, and that hole doping to the m aterial will also result in a HM with high T_c and unusually large m agnetic m om ents at O atom s due to the Stoner instability. The m aterial $Sr_8C aRe_3C u_4O_{24}$ is therefore expected to provide a very useful platform for m aterial design and development, and potential products of the research in this direction can be very useful for spintronics applications.

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TABLE I: Calculated total magnetic moment per unit cell $_{tot}$, magnetic moments inside the mu n-tin spheres of Cul, Cu2 and O2 in units of $_{\rm B}$.

| Doping | tot | Cu1 | Cu2 | 02 |
|--------|-------|------|-------|------|
| 0 | -1.00 | 1.08 | -0.81 | 0.07 |
| 0.05 | -0.60 | 1.06 | -0.81 | 0.12 |
| 0.1 | -0,20 | 1.04 | -0.80 | 0.16 |
| 0.15 | 0.20 | 1.05 | -0.81 | 0.20 |
| 0.2 | 0.60 | 1.04 | -0.80 | 0.25 |
| 0.25 | 1.00 | 1.04 | -0.80 | 0.29 |
| 0.75 | 5.00 | 1.07 | -0.79 | 0.59 |
| 1 | 7.00 | 1.08 | -0.80 | 0.70 |

Figure Captions

Fig. 1: (a) Schem atic picture for the density of states (DOS) of m inority spin e_g orbitals of Cu1 and Cu2, and the partial structure of (010) plane in $Sr_8CaRe_3Cu_4O_{24}$. (b) Schem atic picture for the DOS of m inority spin e_g orbitals of Cu1 and Cu2, and the partial structure of (010) plane expected for $Sr_8CaW_3Cu_4O_{24}$ and $Sr_8CaMo_3Cu_4O_{24}$. (c) Schem atic picture for the DOS of p orbitalof 02 in $Sr_8CaRe_3Cu_4O_{24}$. (d) Schem atic picture for the DOS of p orbital of 02 expected for hole-doped $Sr_8CaRe_3Cu_4O_{24}$. The dotted lines denote the Ferm i level.

Fig. 2: TotalDOS (top) and partialDOS of the m inority spin (spin-up) dorbitals of Cu1 (m iddle) and the m inority spin (spin-down) dorbitals of Cu2 (bottom) of $Sr_8CaW_3Cu_4O_{24}$ with the Ferm i level set at zero.

Fig. 3: TotalDOS of $Sr_8CaM o_3Cu_4O_{24}$ with the Ferm i level set at zero.

Fig. 4: DOS of $(Sr_{0:8}A_{0:2})_8CaRe_3Cu_4O_{24}$ with the Ferm i level set at zero.







